

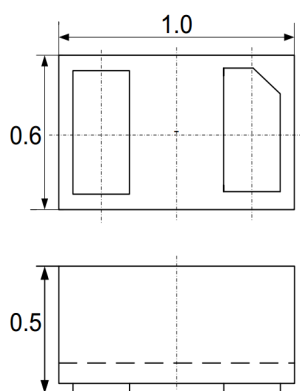
Description

The LE1231P1 is an uni-directional TVS diode, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive data and power line. The LE1231P1 complies with the IEC 61000-4-2 (ESD) standard with $\pm 30\text{kV}$ air and $\pm 30\text{kV}$ contact discharge. It is assembled into an ultra-small 1.0 x 0.6 x 0.5mm lead-free DFN package. The small size and high ESD surge protection make LE1231P1 an ideal choice to protect cell phone, digital cameras, audio players and many other portable applications.

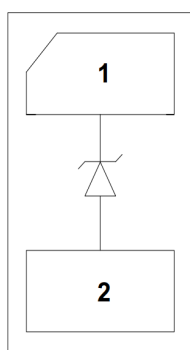
Mechanical Characteristics

- ◆ Package: DFN1006-2 (1.0 x 0.6 x 0.5mm)
- ◆ Case Material: "Green" Molding Compound.
- ◆ Moisture Sensitivity: Level 3 per J-STD-020
- ◆ Terminal Connections: See Diagram Below
- ◆ Marking Information: See Below

Dimensions and Pin Configuration



Package Dimensions



Circuit and Pin Schematic

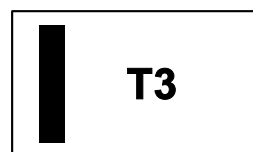
Features

- ◆ Ultra small package: 1.0 x 0.6 x 0.5mm
- ◆ Protects one data or power line
- ◆ Ultra low leakage: nA level
- ◆ Operating voltage: 12V
- ◆ Low clamping voltage
- ◆ 2-pin leadless package
- ◆ Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test
Air discharge: $\pm 30\text{kV}$
Contact discharge: $\pm 30\text{kV}$
 - IEC61000-4-5 (Lightning) 8A (8/20 μs)
- ◆ RoHS Compliant

Applications

- ◆ Cellular Handsets and Accessories
- ◆ Personal Digital Assistants
- ◆ Notebooks and Handhelds
- ◆ Portable Instrumentation
- ◆ Digital Cameras
- ◆ Peripherals
- ◆ Audio Players
- ◆ Keypads, Side Keys, LCD Displays

Marking Information



T3= Device Marking Code
Bar denotes Pin 1

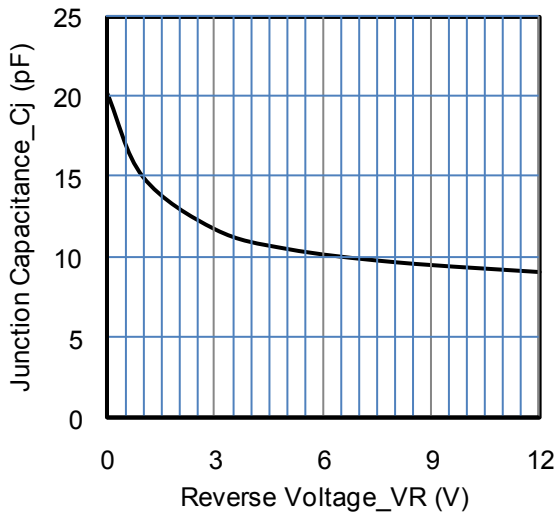
Absolute Maximum Ratings ($T_A=25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	Value	Unit
Peak Pulse Power(8/20 μs)	Ppk	200	W
Peak Pulse Current(8/20 μs)	I _{PP}	8	A
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	V _{ESD}	± 30 ± 30	kV
Operating Temperature Range	T _J	-55 to +125	$^{\circ}\text{C}$
Storage Temperature Range	T _{stg}	-55 to +150	$^{\circ}\text{C}$

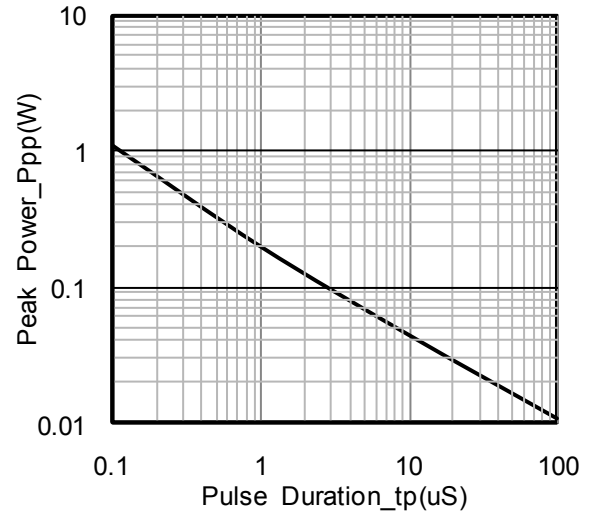
Electrical Characteristics ($T_A=25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	V _{RWM}			12	V	
Breakdown Voltage	V _{BR}	13.3		17.8	V	I _T = 1mA
Reverse Leakage Current	I _R			0.2	μA	V _{RWM} = 12V
Forward Voltage	V _F		1.0	1.2	V	I _F = 10mA
Clamping Voltage	V _C			19	V	I _{PP} = 1A (8 x 20 μs pulse)
Clamping Voltage	V _C			25	V	I _{PP} = 8A (8 x 20 μs pulse)
Junction Capacitance	C _J			60	pF	V _R = 0V, f = 1MHz

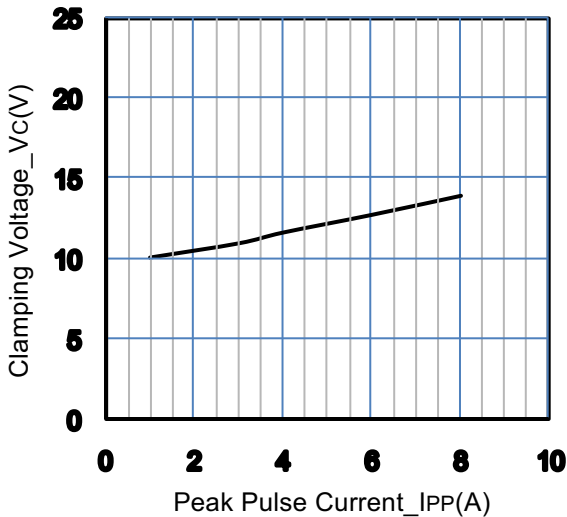
Typical Performance Characteristics (TA=25°C unless otherwise Specified)



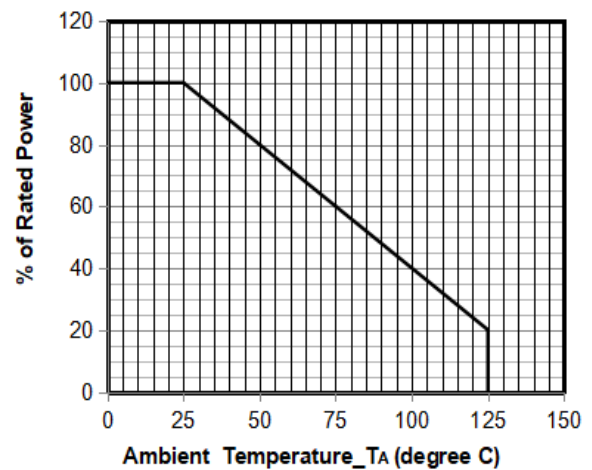
Junction Capacitance vs. Reverse Voltage



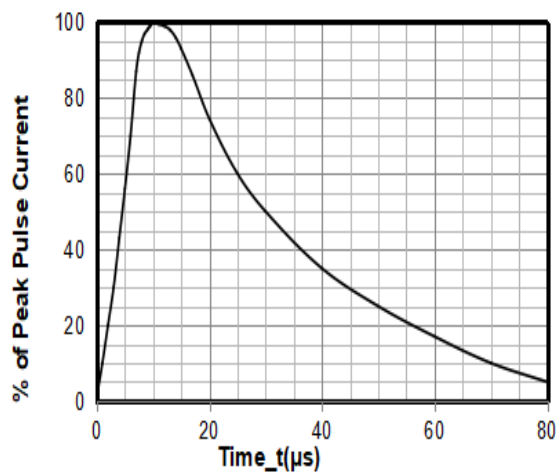
Peak Pulse Power vs. Pulse Time



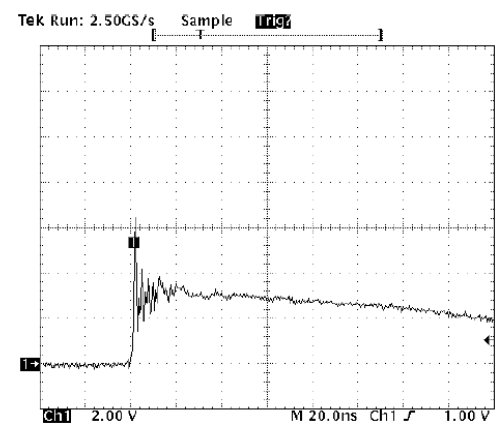
Clamping Voltage vs. Peak Pulse Current



Power Derating Curve



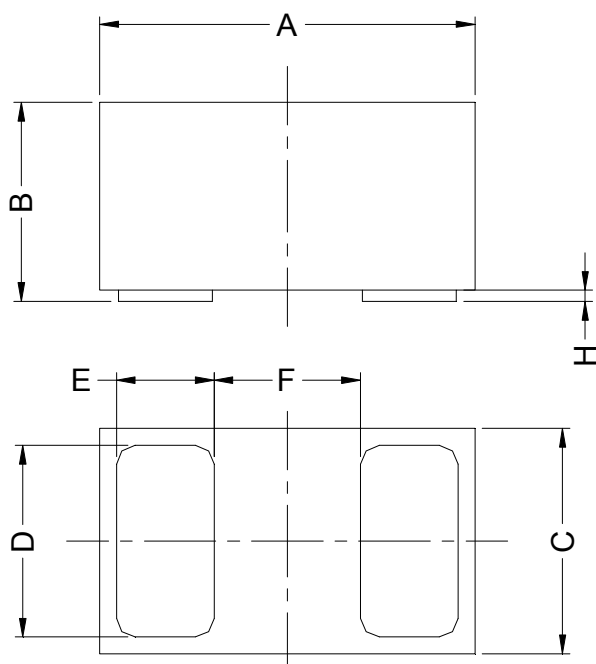
8 X 20μs Pulse Waveform



ESD Clamping Voltage

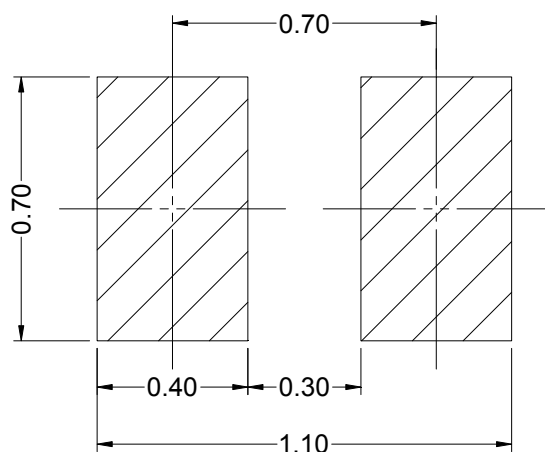
8 kV Contact per IEC61000-4-2

Package Outline Dimensions



DFN1006-2			
Dim	Min	Typ	Max
A	0.95	1.00	1.075
B	0.47	0.50	0.53
C	0.55	0.60	0.675
D	0.45	0.50	0.55
E	0.20	0.25	0.30
F	-	0.40	-
H	0	0.03	0.05
All Dimensions in mm			

Suggested Pad Layout



Unit : mm

Ordering Information

TYPE	REEL	Reel Size	Box	Carton
LE1231P1	10000 pcs	7 Inch	150,000 pcs	600,000 pcs